9 kg of "Trivial Pursuit"?

As an expert in PCB thermal management, I am always interested in posts featuring "Cool" and "Heat." I read the post

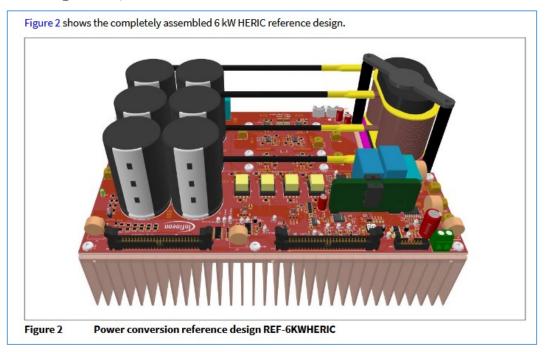
https://www.linkedin.com/posts/bodo%C2%B4s-power-systems powerelectronics-mosfet-solarenergy-activity-7341377481674752004-jAbp?utm source=share&utm medium=member desktop&rcm=ACoAAB6UQegBCzzz-Ho-G88xGrvs4p7g N6JCgM

with great interest and now want to shed some light on the thermal details.

This is our object



Caution: The heat sink and device surfaces of the evaluation or reference board may become hot during testing. Hence, necessary precautions are required while handling the board. Failure to comply may cause injury.



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I obtained the Altium[™] design files, the datasheet¹ (IMDQ75R016M1H), and the User Guide² (UG030541) ("UG") from Infineon.

Datasheet:

2.1.1 Switching devices

The inverter stage is designed with the CoolSiC™ Power Device G1 MOSFET products IMDQ75R016M1H.

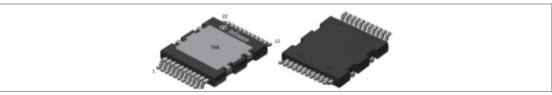


Figure 8 IMDQ75R016M1H

IMDQ75R016M1H belongs to the CoolSiC[™] Power Device 750 V G1 family. The 750 V CoolSiC[™] MOSFET offers excellent performance in this design due to its low switching losses, stable conduction loss overtemperature, and ease of thermal management. It is an ideal part for hybrid inverter applications which are typically passive cooled and sealed from the environment.

Table 3 Thermal characteris	tics						
Parameter	Cumbal	Values			Unit	Note / Test Condition	
Faranietei	Symbol	Min.	Тур.	Max.	Ullit	Note / Test Condition	
Thermal resistance, junction - case	R _{th(j-c)}	-	-	0.39	°C/W	Not subject to production test. Parameter verified by design/characterization according to JESD51-14.	

User Guide:

6 kW HERIC reference design user guide REF-6KW HERIC design for solar photovoltaic solutions **Board layout** 5 **Board layout REF-6KWHERIC** 5.1 Mechanical data Table 11 Dimensions 250 mm x 155 mm No. of layers **Copper thickness** 77.36 mil Weight 9.02 kg

¹ www.infineon.com/dgdl/Infineon-IMDQ75R016M1H-DataSheet-v02 00-EN.pdf

² https://www.infineon.com/assets/row/public/documents/24/44/infineon-ref-6kwheric-usermanual-en.pdf



The geometric model of the assembly can be generated quickly and reliably from the AltiumTM files using our software³ in just two clicks. Finding the thermal conditions, however, is more work.

Quote: "This reference design is not a qualified and certified commercial product."

My goal is to make you aware of typical thermal issues. I want to reproduce the reported measurements via simulation.

Data:

- In Fig. 2 of the UG, four prominent yellow blocks are visible. These are **not MOSFETs** but **transformers**.
- The six CoolSiC MOSFETs are located on the **bottom side of the board**.
- These CoolSiCs are optimized for top-side cooling (Rth_JC = 0.39 K/W, datasheet).
- Therefore, there are **no thermal vias**.
- A 9 kg (!) finned heatsink is mounted on the bottom side to absorb heat from the component surfaces.
- The UG does not mention whether the heatsink baseplate is specially shaped or adapted, nor what type of thermal adhesive is used.
- The advantage of CoolSiC: "Using SiC MOSFETs enables switching at a higher frequency, resulting in a significant reduction in ... heatsink size."
- To calculate anything related to temperature, we need the **power losses**.

 Unfortunately, the UG does not provide the watts generated by the CoolSiCs.

 It's a pity that the UG only focuses on electrical details!
- From a 6 kW line with ~98.5% efficiency, I assume losses of approx. 90 W (Tab. 8 @ 380 V), which I distribute evenly across Q1, Q2, Q3, and Q4.

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³ TRM3. www.adam-research.com



Input volt	ages	380 V _{DC} , 44	5 V _{DC} , and 510	V _{DC}					
PWM		50 kHz							
Output po	wer	6 kW, V _{out} =230 V _{rms} / 50 Hz							
Table 9	Test d	ata							
•	Input Current	Input Power	Output	Output	Output	PF	iTHD	Efficiency	
voltage	1 -		Output Voltage (V _{I-I rms})			PF	iTHD	Efficiency	
Input voltage (V _{dc})	Current	Power	Voltage	Power	Current	PF 0.9993	iTHD	Efficiency	

• The contributions of other components is unknown and is not included in the calculation model. It would be useful to know how many watts Q5 and Q6 contribute.

6.01

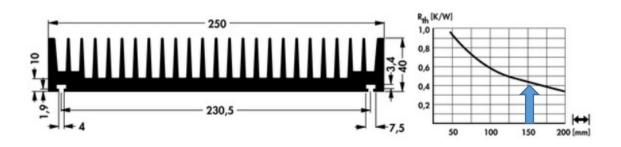
26.14

0.9992

1.764

98.45

- From Fig. 2 UG, I estimate the heatsink dimensions to be width 250 mm, length 150 mm, height 40 mm.
- From Fischer Elektronik GmbH catalog, I select **SK91 75 AL**⁴ (unoxidized, suitable for outdoor installation) with these dimensions, giving an R_{Θ} of ≈ 0.4 K/W at 150 mm length.



-

510

12.02

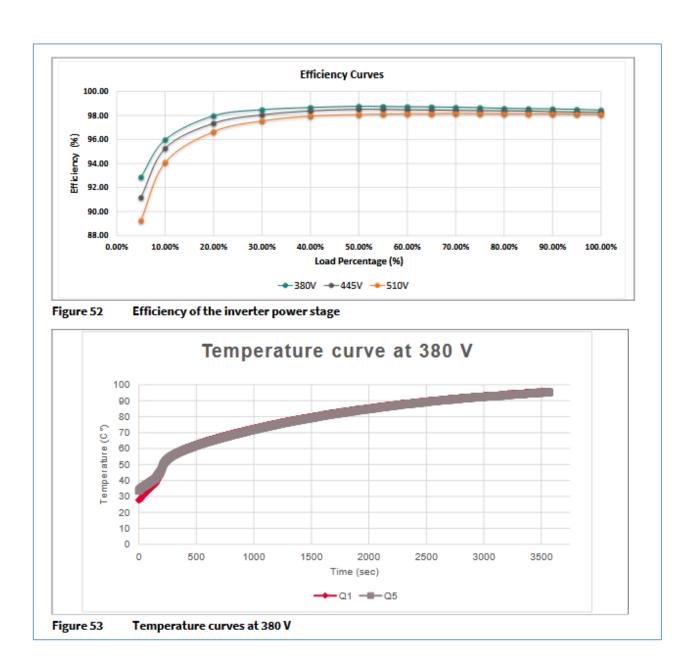
6.1

230

⁴ https://www.fischerelektronik.de/web_fischer/de_DE/VA/SK91150SA/datasheet.xhtml



Measurements:



- The UG does not show how or where measurements were taken.
- Fig. 53: Measured temperature is approx. 100 °C in steady state @ 380 V.
- Fig. 53: Ambient temperature appears to be approx. 30 °C.



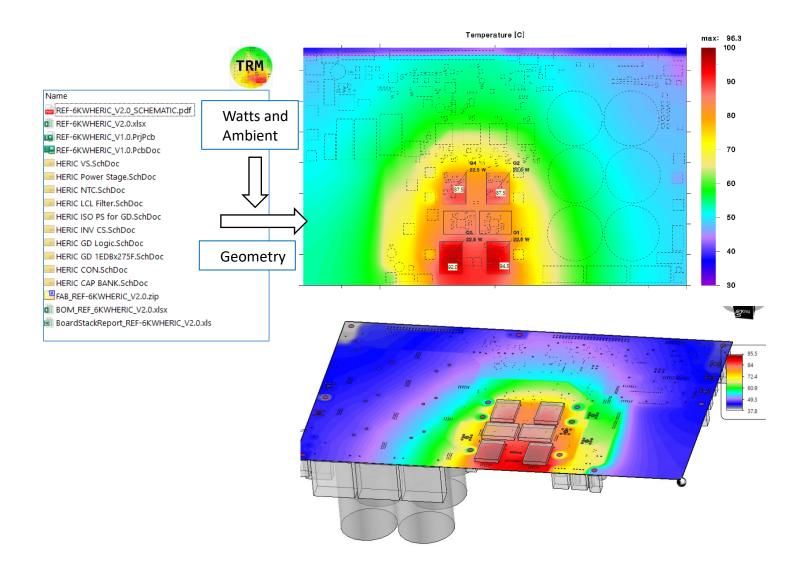
Simulation results:

• TRM simulation results for temperature are around 90 °C:

Q1: 93 °CQ2: 85 °CQ3: 94 °CQ4: 86 °C

Not bad at all, considering the many assumptions and the fact that not all heat sources are known and are not included.

• Q1 and Q3 are too close to the edge of the heatsink. It's generally recommended to position the hottest components as centrally as possible.





Summary:

- The temperature of the CoolSiCs strongly depends on the effectiveness of the heatsink.
- Therefore, the UG should also provide better information about the thermal losses of the circuit.
- If the assembly is to weigh less than 9 kg, alternatives like a fan or water cooling should be considered.

Trivial pleasure? For me, it was real.

For more information:

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